

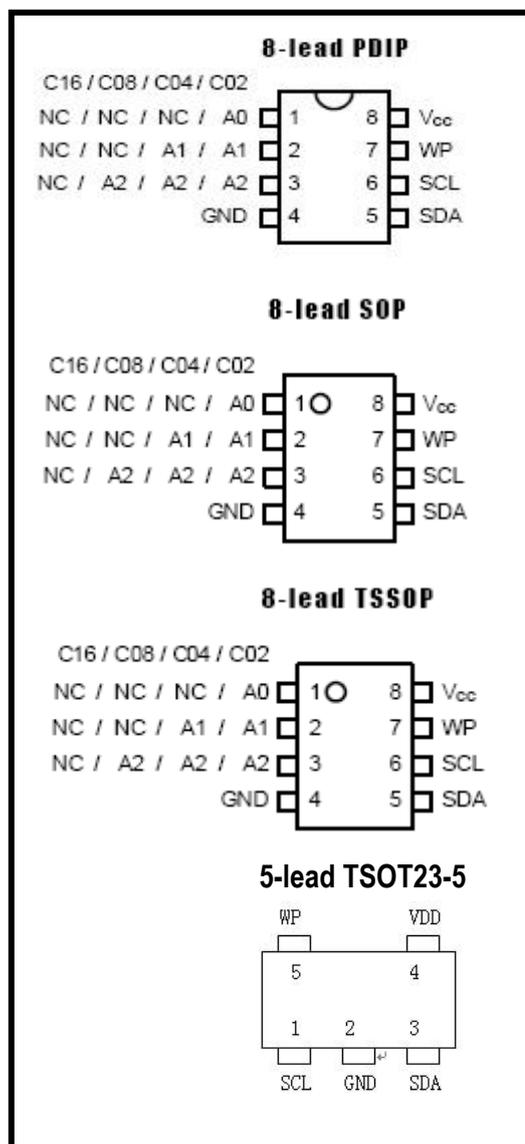
BL24C02/BL24C04/BL24C08/BL24C16

2K bits (256 X 8) / 4K bits (512 X 8) / 8K bits (1024 X 8) / 16K bits (2048 X 8)

Two-wire Serial EEPROM

■ Features

- Two-wire Serial Interface
- $V_{CC} = 1.7V$ to $5.5V$
- Bi-directional Data Transfer Protocol
- Internally Organized
 - BL24C02, 256 X 8 (2K bits)
 - BL24C04, 512 X 8 (4K bits)
 - BL24C08, 1024 X 8 (8K bits)
 - BL24C16, 2048 X 8 (16K bits)
- 1 MHz (5V), 400 kHz (1.8V, 2.5V, 2.7V) Compatibility
- 8-byte Page (2K), 16-byte Page (4K, 8K, 16K) Write Modes
- Self-timed Write Cycle (5 ms max)
- 1 Million Write Cycles guaranteed
- Data Retention > 100 Years
- Operating Temperature: $-40^{\circ}C$ to $+85^{\circ}C$
- 8-lead PDIP, 8-lead SOP, 5-lead TSOT 23-5 and 8-lead TSSOP Packages



■ Description

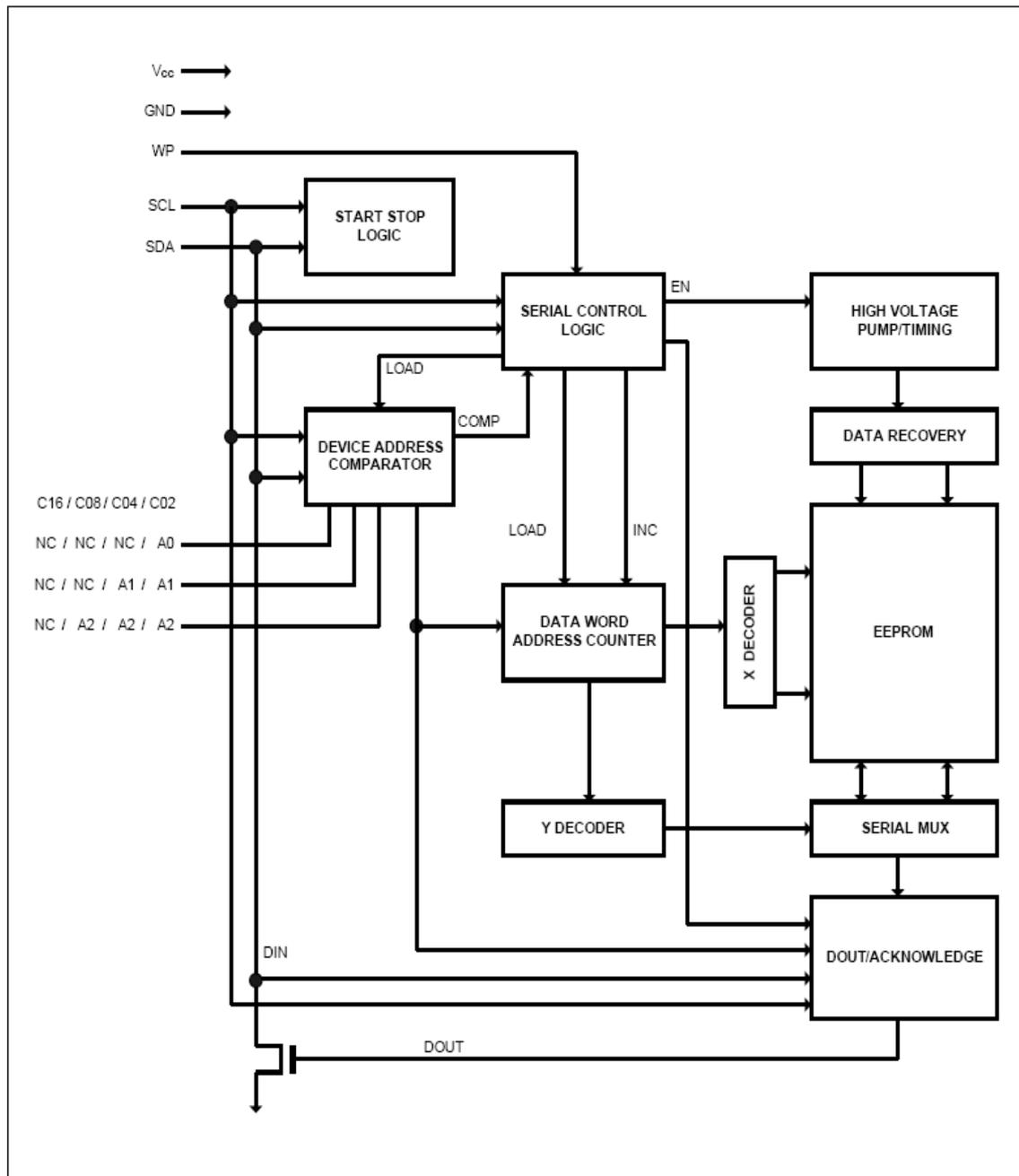
BL24C02/BL24C04/BL24C08/BL24C16 provides 2048/4096/8192/16384 bits of serial electrically erasable and programmable read-only memory (EEPROM) organized as 256/512/1024/2048 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The BL24C02/BL24C04/BL24C08/BL24C16 is available in space-saving 8-lead PDIP, 8-lead SOP, 8-lead TSSOP and 5-lead TSOT23-5 packages and is accessed via a two-wire serial interface.

Pin Descriptions

Table 1: Pin Configuration

Pin Designation	Type	Name and Functions
A0 - A2	I	Address Inputs
SDA	I/O & Open-drain	Serial Data
SCL	I	Serial Clock Input
WP	I	Write Protect
GND	P	Ground
Vcc	P	Power Supply
NC	NC	No Connect

Block Diagram



DEVICE/PAGE ADDRESSES (A2, A1 and A0): The A2, A1 and A0 pins are device address inputs that are hard wired for the BL24C02. Eight 2K devices may be addressed on a single bus system (device addressing is discussed in detail under the Device Addressing section).

The BL24C04 uses the A2 and A1 inputs for hard wire addressing and a total of four 4K devices may be addressed on a single bus system. The A0 pin is a no connect and can be connected to ground.

The BL24C08 only uses the A2 input for hardwire addressing and a total of two 8K devices may be addressed on a single bus system. The A0 and A1 pins are no connects and can be connected to ground.

The BL24C16 does not use the device address pins, which limits the number of devices on a single bus to one. The A0, A1 and A2 pins are no connects and can be connected to ground.

SERIAL DATA (SDA): The SDA pin is bi-directional for serial data transfer. This pin is open-drain driven and may be wire-ORed with any number of other open-drain or open- collector devices.

SERIAL CLOCK (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

WRITE PROTECT (WP): The BL24C02/BL24C04/BL24C08/BL24C16 has a Write Protect pin that provides hardware data protection. The Write Protect pin allows normal read/write operations when connected to ground (GND). When the Write Protect pin is connected to VCC, the write protection feature is enabled and operates as shown in the following Table 2.

WP Pin Status:	Part of the Array Protected			
	BL24C02	BL 24C04	BL 24C08	BL 24C16
At V _{CC}	Full (2K) Array	Full (4K) Array	Full (8K) Array	Full (16K) Array
At GND	Normal Read/Write Operations			

■ Memory Organization

BL24C02, 2K SERIAL EEPROM: Internally organized with 32 pages of 8 bytes each, the 2K requires an 8-bit data word address for random word addressing.

BL24C04, 4K SERIAL EEPROM: Internally organized with 32 pages of 16 bytes each, the 4K requires a 9-bit data word address for random word addressing.

BL24C08, 8K SERIAL EEPROM: Internally organized with 64 pages of 16 bytes each, the 8K requires a 10-bit data word address for random word addressing.

BL24C16, 16K SERIAL EEPROM: Internally organized with 128 pages of 16 bytes each, the 16K requires an 11-bit data word address for random word addressing.

■ Device Operation

CLOCK and DATA TRANSITIONS: The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see to Figure 1 on page 4). Data changes during SCL high periods will indicate a start or stop condition as defined below.

START CONDITION: A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see to Figure 2 on page 4).

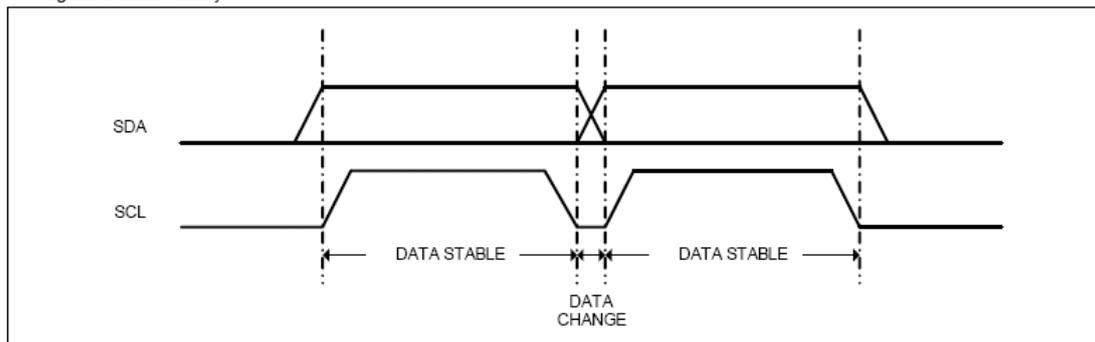
STOP CONDITION: A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (see Figure 2 on page 4).

ACKNOWLEDGE: All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a "0" to acknowledge that it has received each word. This happens during the ninth clock cycle. **STANDBY MODE:** The K24C02/K24C04/K24C08/K24C16 features a low-power standby mode which is enabled: (a) upon power-up and (b) after the receipt of the STOP bit and the completion of any internal operations

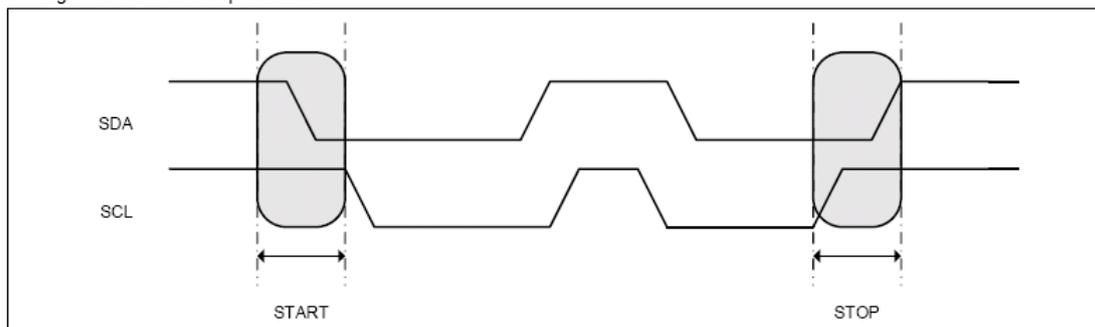
MEMORY RESET: After an interruption in protocol, power loss or system reset, any two-wire part can be reset by following these steps:

1. Clock up to 9 cycles.
2. Look for SDA high in each cycle while SCL is high.
3. Create a start condition.

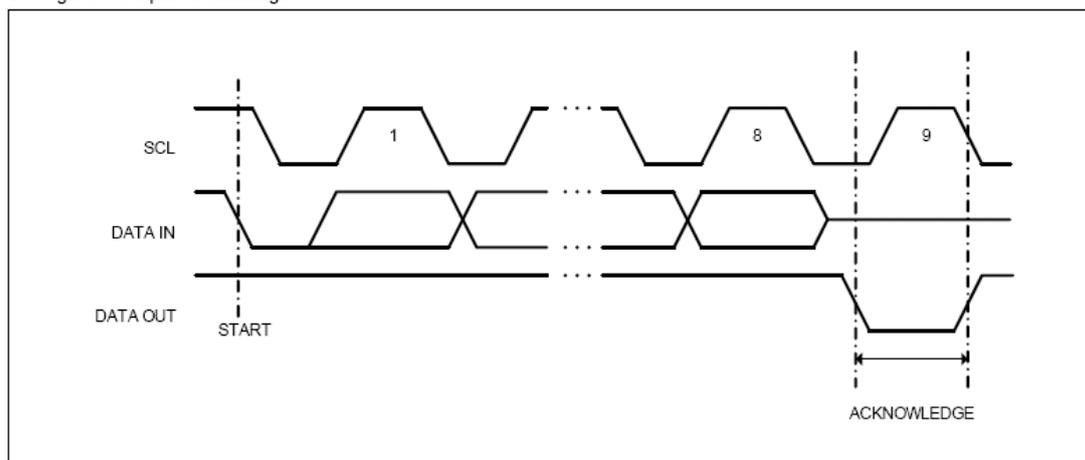
● Figure 1: Data Validity



● Figure 2: Start and Stop Definition



● Figure 3: Output Acknowledge



■ Device Addressing

The 2K, 4K, 8K and 16K EEPROM devices all require an 8-bit device address word following a start condition to enable the chip for a read or write operation (see to Figure 4 on page 7).

The device address word consists of a mandatory "1", "0" sequence for the first four most significant bits as shown. This is common to all the Serial EEPROM devices.

The next 3 bits are the A2, A1 and A0 device address bits for the 2K EEPROM. These 3 bits must compare to their corresponding hardwired input pins.

The 4K EEPROM only uses the A2 and A1 device address bits with the third bit being a memory page address bit. The two device address bits must compare to their corresponding hardwired input pins. The A0 pin is no connect.

The 8K EEPROM only uses the A2 device address bit with the next 2 bits being for memory page addressing. The A2 bit must compare to its corresponding hard-wired input pin. The A1 and A0 pins are no connect.

The 16K does not use any device address bits but instead the 3 bits are used for memory page addressing. These page addressing bits on the 4K, 8K and 16K devices should be considered the most significant bits of the data word address which follows. The A0, A1 and A2 pins are no connect.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon a compare of the device address, the EEPROM will output a "0". If a compare is not made, the chip will return to a standby state.

■ Write Operations

BYTE WRITE: A write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a "0" and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a "0" and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally timed write cycle, t_{WR} , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (see Figure 5 on page 7).

PAGE WRITE: The 2K EEPROM is capable of an 8-byte page write, and the 4K, 8K and 16K devices are capable of 16-byte page writes.

A page write is initiated the same as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to seven (2K) or fifteen (4K, 8K, 16K) more data words. The EEPROM will respond with a "0" after each data word received. The microcontroller must terminate the page write sequence with a stop condition (see Figure 6 on page 7).

The data word address lower three (2K) or four (4K, 8K, 16K) bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than eight (2K) or sixteen (4K, 8K, 16K) data words are transmitted to the EEPROM, the data word address will "roll over" and previous data will be overwritten.

ACKNOWLEDGE POLLING: Once the internally timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a "0", allowing the read or write sequence to continue.

■ Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to "1". There are three read operations: current address read, random address read and sequential read.

CURRENT ADDRESS READ: The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address "roll over" during read is from the last byte of the last memory page to the first byte of the first page. The address "roll over" during write is from the last byte of the current page to the first byte of the same page.

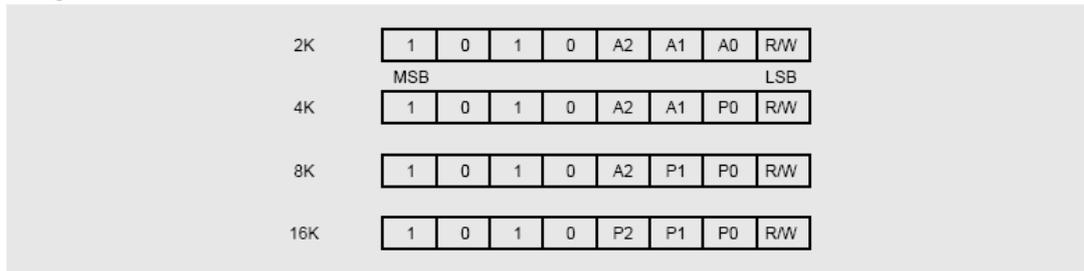
Once the device address with the read/write select bit set to "1" is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input "0" but does generate a following stop condition (see Figure 7 on page 8).

Read Operations

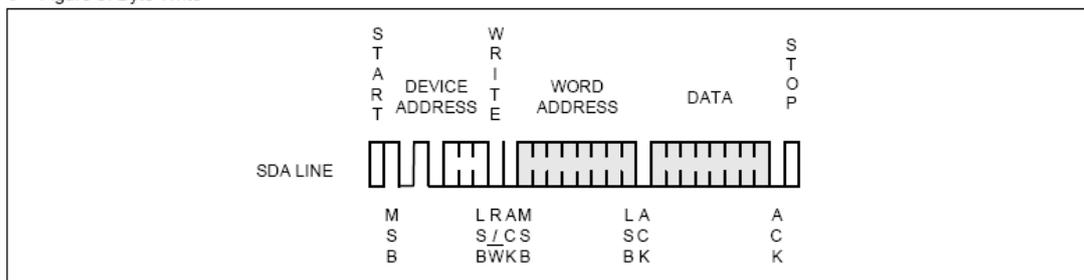
RANDOM READ: A random read requires a "dummy" byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a "0" but does generate a following stop condition (see Figure 8 on page 8).

SEQUENTIAL READ: Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will "roll over" and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a "0" but does generate a following stop condition (see Figure 9 on page 8).

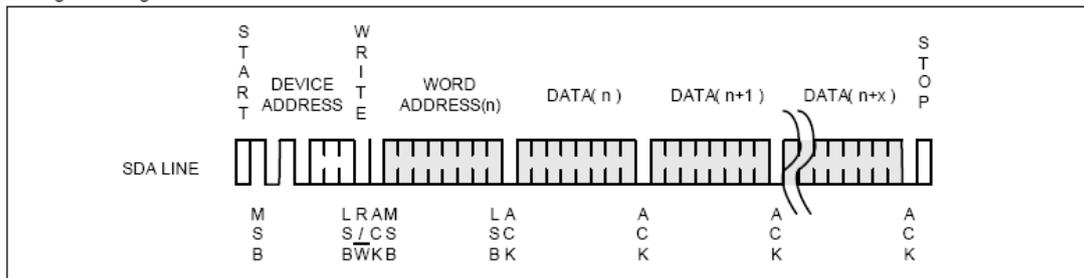
● Figure 4: Device Address



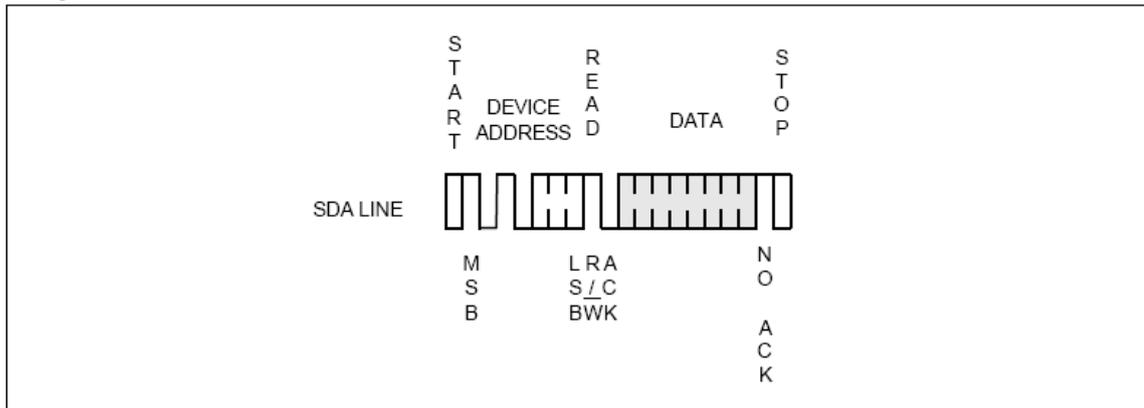
● Figure 5: Byte Write



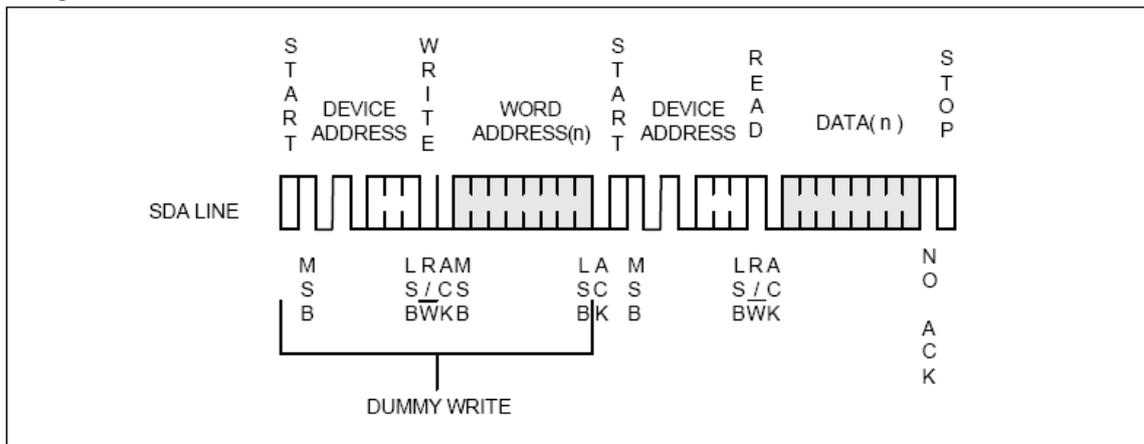
● Figure 6: Page Write



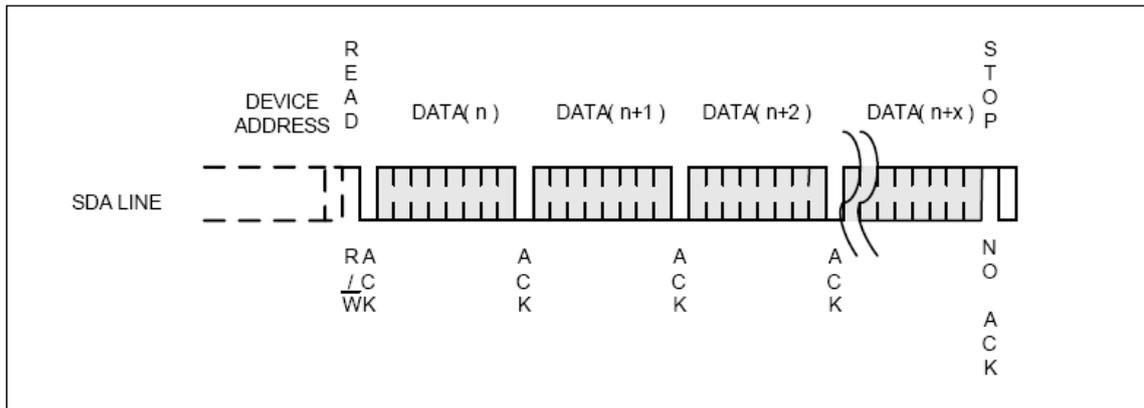
● Figure 7: Current Address Read



● Figure 8: Random Read



● Figure 9: Sequential Read



■ Electrical Characteristics

- **Absolute Maximum Stress Ratings**

DC Supply Voltage-0.3V to +6.5V

Input / Output VoltageGND-0.3V to V_{CC}+0.3V

Operating Ambient Temperature -40°C to +85°C

Storage Temperature -65°C to +150°C

- **Comments**

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

■ DC Electrical Characteristics

- Applicable over recommended operating range from: T_A = -40 °C to +85 °C, V_{CC} = 1.7V to +5.5V (unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Supply Voltage	V _{CC}	1.7	-	5.5	V	
Supply Current V _{CC} = 5.0V	I _{CC1}	-	0.4	1.0	mA	READ at 100 kHz
Supply Current V _{CC} = 5.0V	I _{CC2}	-	2.0	3.0	mA	WRITE at 100 kHz
Standby Current	I _{SA}	-	-	1.0	μA	V _{IN} = V _{CC} or GND
Input Leakage Current	I _{LI}	-	-	3.0	μA	V _{IN} = V _{CC} or GND
Output Leakage Current	I _{LO}	-	0.05	3.0	μA	V _{OUT} = V _{CC} or GND
Input Low Level	V _{IL}	-0.6	-	V _{CC} X 0.3	V	
Input High Level	V _{IH}	V _{CC} X 0.7	-	V _{CC} + 0.5	V	
Output Low Level V _{CC} =5.0V	V _{OL3}	-	-	0.4	V	I _{OL} = 3.0 mA
Output Low Level V _{CC} =3.0V	V _{OL2}	-	-	0.4	V	I _{OL} = 2.1 mA
Output Low Level V _{CC} =1.7V	V _{OL1}	-	-	0.2	V	I _{OL} = 0.15 mA

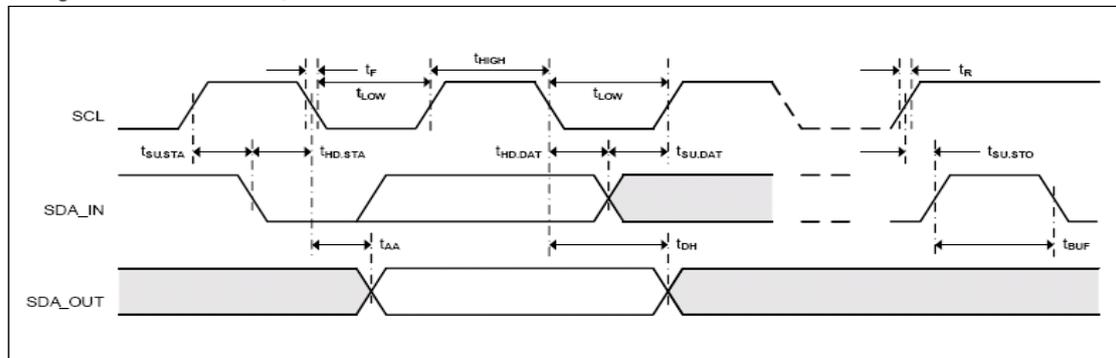
AC Electrical Characteristics

- Applicable over recommended operating range from $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = +1.8\text{V}$ to $+5.5\text{V}$, $CL = 1$ TTL Gate and 100 pF (unless otherwise noted)

Parameter	Symbol	1.8-volt			5.0-volt			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Clock Frequency, SCL	f_{SCL}	-	-	400	-	-	1000	kHz
Clock Pulse Width Low	t_{LOW}	1.2	-	-	0.6	-	-	μs
Clock Pulse Width High	t_{HIGH}	0.6	-	-	0.4	-	-	μs
Noise Suppression Time	t_i	-	-	50	-	-	40	μs
Clock Low to Data Out Valid	t_{AA}	0.05	-	0.9	0.05	-	0.55	μs
Time the bus must be free before a new transmission can start	t_{BUF}	1.2	-	-	0.5	-	-	μs
Start Hold Time	$t_{HD,STA}$	0.6	-	-	0.25	-	-	μs
Start Setup Time	$t_{SU,STA}$	0.6	-	-	0.25	-	-	μs
Data In Hold Time	$t_{HD,DAT}$	0	-	-	0	-	-	μs
Data In Setup Time	$t_{SU,DAT}$	100	-	-	100	-	-	ns
Inputs Rise Time(1)	t_R	-	-	0.3	-	-	0.3	μs
Inputs Fall Time(1)	t_F	-	-	300	-	-	100	ns
Stop Setup Time	$t_{SU,STO}$	0.6	-	-	0.25	-	-	μs
Data Out Hold Time	t_{DH}	50	-	-	50	-	-	ns
Write Cycle Time	t_{WR}	-	-	5	-	-	5	ms
5.0V, 25°C , Byte Mode	Endurance	1M	-	-	-	-	-	Write Cycles

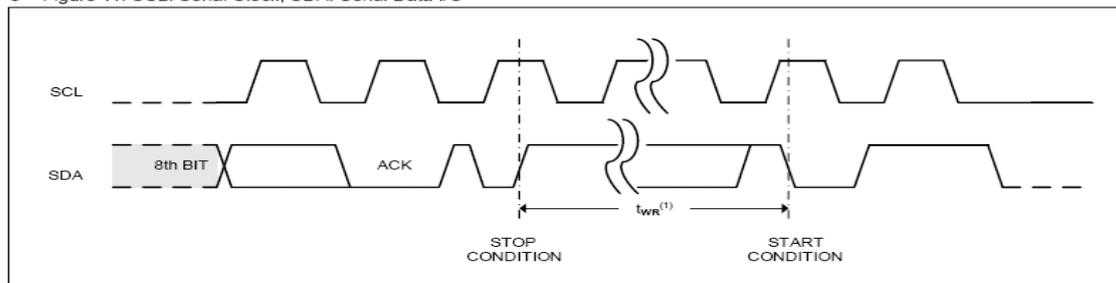
Bus Timing

- Figure 10: SCL: Serial Clock, SDA: Serial Data I/O



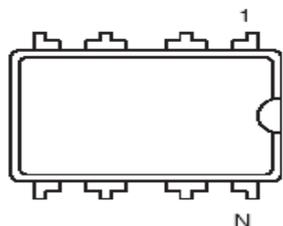
Write Cycle Timing

- Figure 11: SCL: Serial Clock, SDA: Serial Data I/O

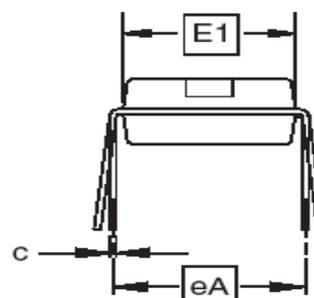


Package Information

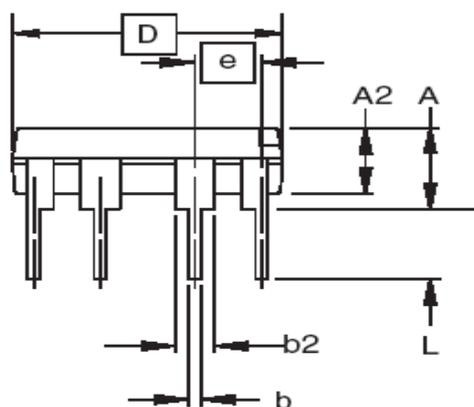
8-lead PDIP Outline Dimensions



Top View



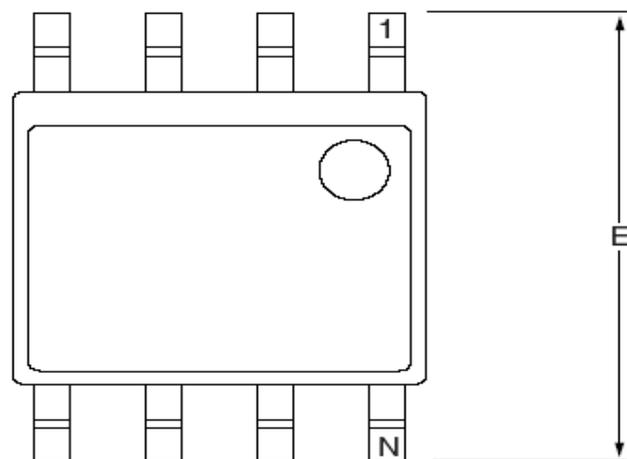
End View



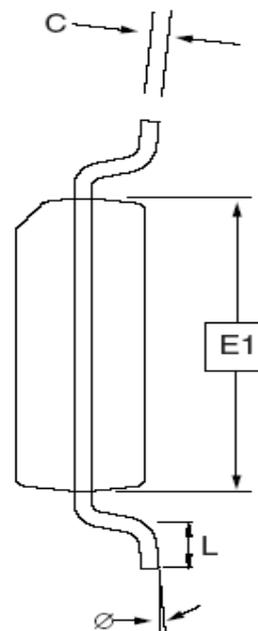
Side View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	3.60	3.80	4.00
A2	3.10	3.30	3.50
b	0.44	-	0.53
B1	1.52BSC		
c	0.25	-	0.31
c1	0.24	0.25	0.26
D	9.05	9.25	9.45
E1	6.15	6.35	6.55
e	2.54BSC		
eA	7.62BSC		
L	3.00	-	-

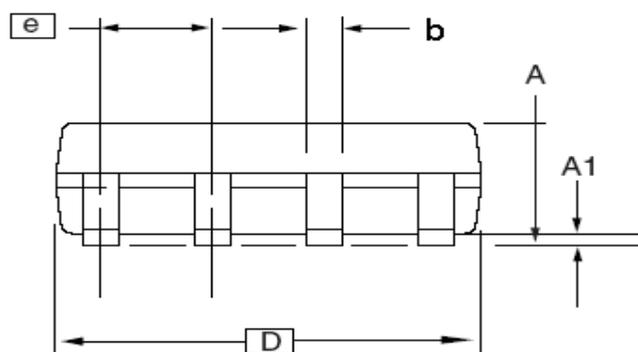
8-lead SOP Outline Dimensions



Top View



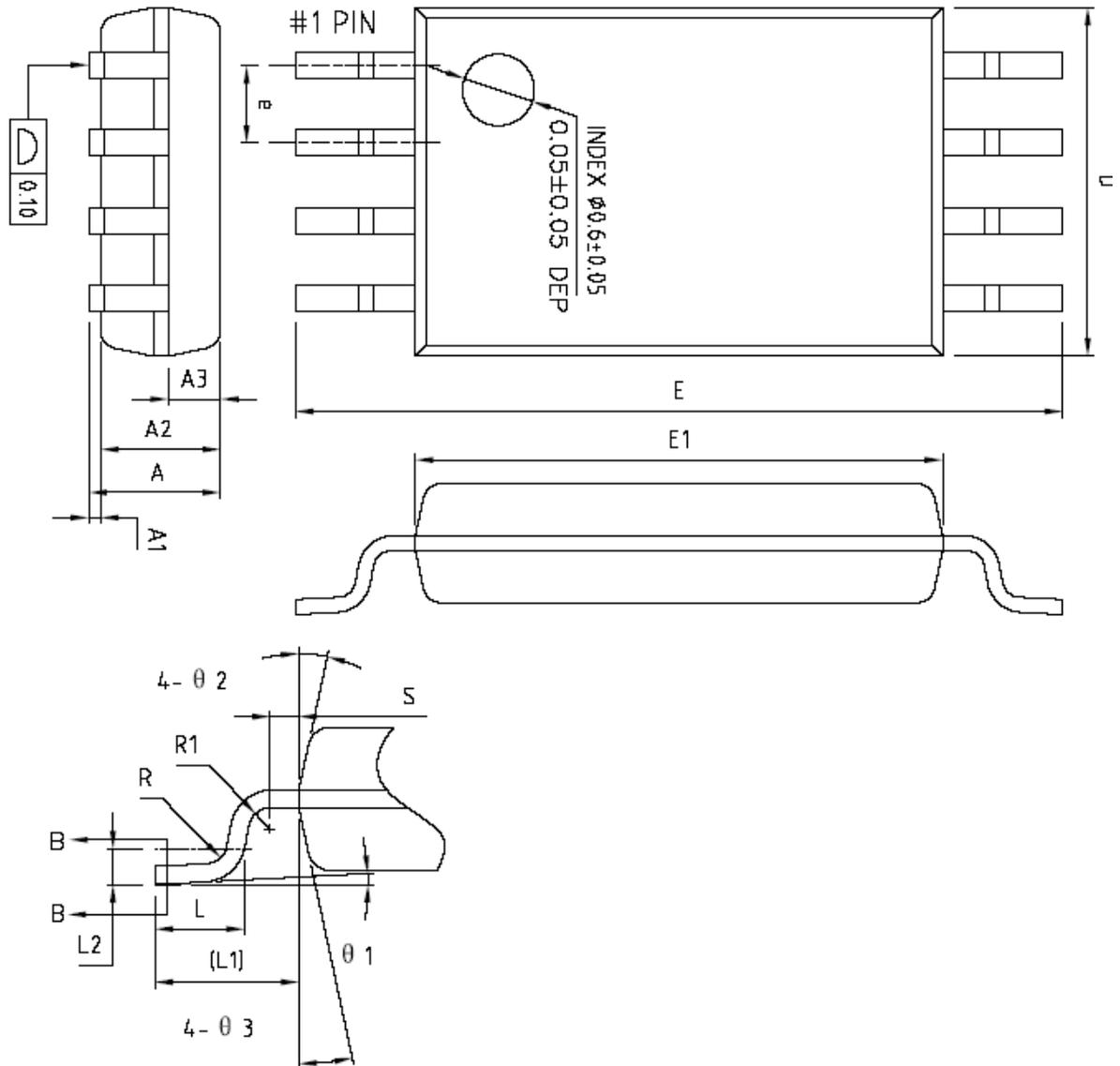
End View



Side View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	-	-	1.77
A1	0.08	0.18	0.28
b	0.44	-	0.53
c	0.21	-	0.26
D	4.70	4.90	5.10
E	5.80	6.00	6.20
E1	3.70	3.90	4.10
e	1.27BSC		
θ	0	-	8°

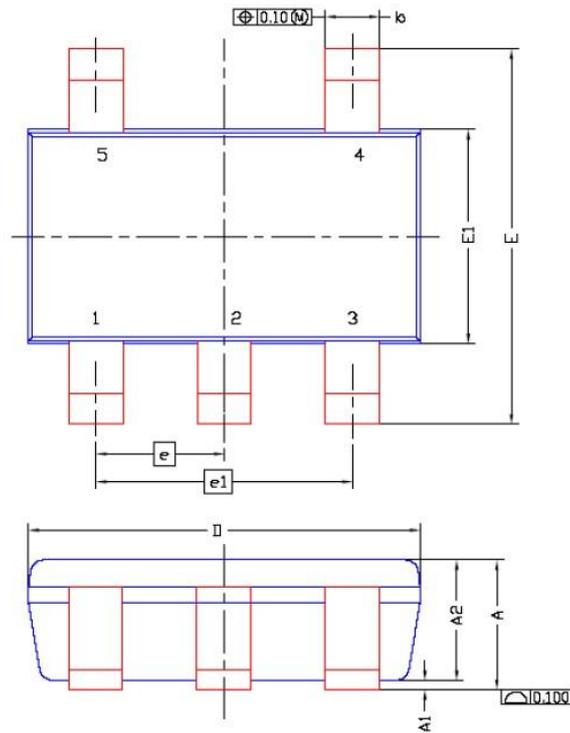
8-lead TSSOP Outline Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	-	0.28
b1	0.20	0.22	0.24
c	0.10	-	0.19
c1	0.10	0.13	0.15

D	2.83	2.93	3.03
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00REF		
L2	0.25BSC		
R	0.09	-	-
R1	0.09	-	-
S	0.20	-	-
Ø1	0°	-	8°
Ø2	10°	12°	14°
Ø3	10°	12°	14°

5-lead TSOT23-5 Outline Dimensions



DIM.	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.95	1.00	0.0315	0.0374	0.0394
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.875	0.90	0.0276	0.0344	0.0354
b	0.35	0.40	0.50	0.014	0.016	0.020
c	0.10	0.127	0.20	0.004	0.005	0.008
D	2.90 BSC			0.114 BSC		
E	2.80 BSC			0.110 BSC		
E1	1.60 BSC			0.063 BSC		
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
L	0.30	0.40	0.60	0.0118	0.0157	0.024
L1	0.60REF			0.024REF		
L2	0.254BSC			0.010BSC		
R	0.10	---	---	0.004	---	---
θ	0°	4°	8°	0°	4°	8°
θ1	7°NOM			7°NOM		

